1.6±0.05

1.2±0.05

ÈS6

6±0.05

単位: mm

5

4.Source2

5.Gate2

6.Drain1

2-2N1D

 0.2 ± 0.05

TOSHIBA Field-Effect Transistor Silicon N-Channel MOS Type

SSM6N42FE

- Power Management Switch Applications
- High-Speed Switching Applications
- 1.5V drive
- N-ch 2-in-1
- Low ON-resistance : $R_{DS(ON)}$ = 600 m Ω (max) (@V_{GS} = 1.5V)
 - : $R_{DS(ON)} = 450 \text{ m}\Omega \text{ (max) (@V_{GS} = 1.8V)}$
 - : $R_{DS(ON)}$ = 330 m Ω (max) (@V_{GS} = 2.5V)
 - : $R_{DS(ON)} = 240 \text{ m}\Omega \text{ (max) (@V_{GS} = 4.5V)}$

Absolute Maximum Ratings (Ta = 25°C) (Q1, Q2 Common)

Characteristic		Symbol	Rating	Unit	
Drain-source voltage		V_{DSS}	20	V	
Gate-source voltage		V_{GSS}	± 10	V	
Drain current	DC	I _D (Note 1)	800	mA	
	Pulse	I _{DP} (Note 1)	1600	IIIA	
Drain power dissipation		P _D (Note 2)	150	mW	
Channel temperature		T _{ch}	150	/%C	
Storage temperature		T _{stg}	-55 to 150	∘c	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e.

Weight: 3.0 mg (typ.)

JEDEC JEITA TOSHIBA 1.Source1

2.Gate1

3.Drain2

operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

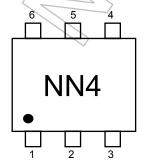
Note 1: The junction temperature should not exceed 150°C during use.

Note 2: Total rating

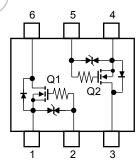
Mounted on an FR4 board

 $(25.4 \text{ mm} \times 25.4 \text{ mm} \times 1.6 \text{ mm}, \text{ Cu Pad: } 0.135 \text{ mm}^2 \times 6)$

Marking



Equivalent Circuit (top view)



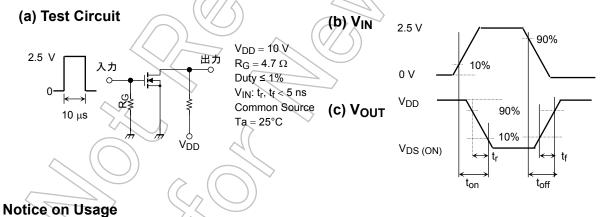
Start of commercial production 2009-11

Electrical Characteristics (Ta = 25°C) (Q1, Q2 Common)

Chara	racteristic Symbol Test Condition		Min	Тур.	Max	Unit	
Drain-source breakdown voltage	V (BR) DSS	I _D = 1 mA, V _{GS} = 0 V	20	_	_	V	
	V (BR) DSX	I _D = 1 mA, V _{GS} = -10 V	12	_	_] '	
Drain cutoff current		I _{DSS}	V _{DS} = 20 V, V _{GS} = 0 V	1	_	1	μА
Gate leakage curre	ent	I _{GSS}	V _{GS} = ±8 V, V _{DS} = 0 V	(<u> </u>	±1	μА
Gate threshold vol	tage	V _{th}	V _{DS} = 3 V, I _D = 1 mA	0.35	グ ー	1.0	V
Forward transfer a	dmittance	Y _{fs}	V _{DS} = 3 V, I _D = 500 mA (Note 3)	1.05	2.1	_	S
		R _{DS} (ON)	$I_D = 500 \text{ mA}, V_{GS} = 4.5 \text{ V}$ (Note 3)	9	185	240	- mΩ
Drain-source ON-resistance	$I_D = 400 \text{ mA}, V_{GS} = 2.5 \text{ V}$ (Note 3)		> —	245	330		
	I _D = 250 mA, V _{GS} = 1.8 V (Note 3)		_	310	450		
	$I_D = 150 \text{ mA}, V_{GS} = 1.5 \text{ V}$ (Note 3)		_	370	600		
Input capacitance Output capacitance		C _{iss}		- /	90	. —	pF
		Coss	V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz	> -((21		
Reverse transfer capacitance		C _{rss}		4	15//		
Total Gate Charge Gate-Source Charge		Qg	V _{DS} = 10 V, I _D = 0.8 A V _{GS} = 4.5 V		2.00	_	nC
		Q _{gs}			1.02		
Gate-Drain Charge		Q _{gd}	V6S-4.3 V	$\langle - \rangle$	0.98	_	
Switching time	Turn-on time	t _{on}	V _{DD} = 10 V, I _D = 200 mA	Ú –	18	_	ns
	Turn-off time	t _{off}	V_{GS} = 0 to 2.5 V, R_{G} = 4.7 Ω	_	50	_	
Drain-source forwa	ard voltage	V _{D\$F}	$I_D = -0.8 \text{ A}, V_{GS} = 0 \text{ V}$ (Note 3)	_	-0.84	-1.2	V

Note 3: Pulse test

Switching Time Test Circuit (Q1, Q2 Common)



Let V_{th} be the voltage applied between gate and source that causes the drain current (I_D) to be low (1 mA for the SSM6N42FE). Then, for normal switching operation, $V_{GS(on)}$ must be higher than V_{th} , and $V_{GS(off)}$ must be lower than V_{th} . This relationship can be expressed as: $V_{GS(off)} < V_{th} < V_{GS(on)}$.

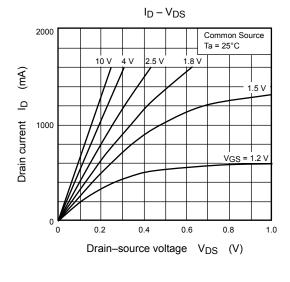
Take this into consideration when using the device.

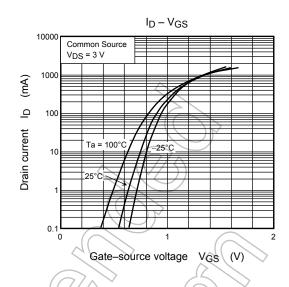
Handling Precaution

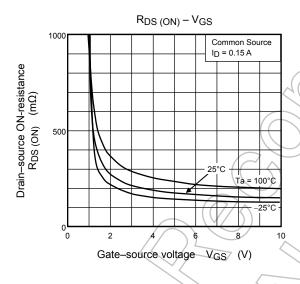
When handling individual devices that are not yet mounted on a circuit board, make sure that the environment is protected against electrostatic discharge. Operators should wear antistatic clothing, and containers and other objects that come into direct contact with devices should be made of antistatic materials.

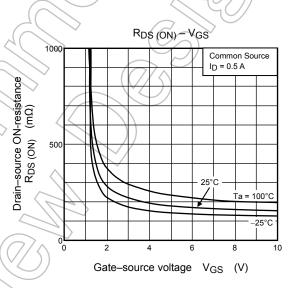
2 2014-03-01

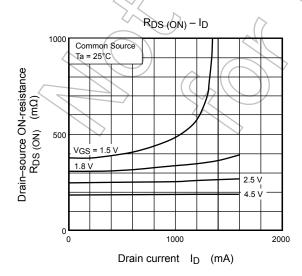
Q1, Q2 Common

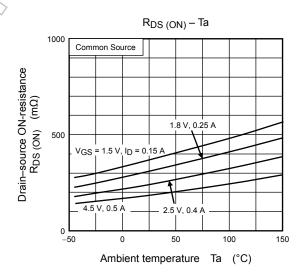






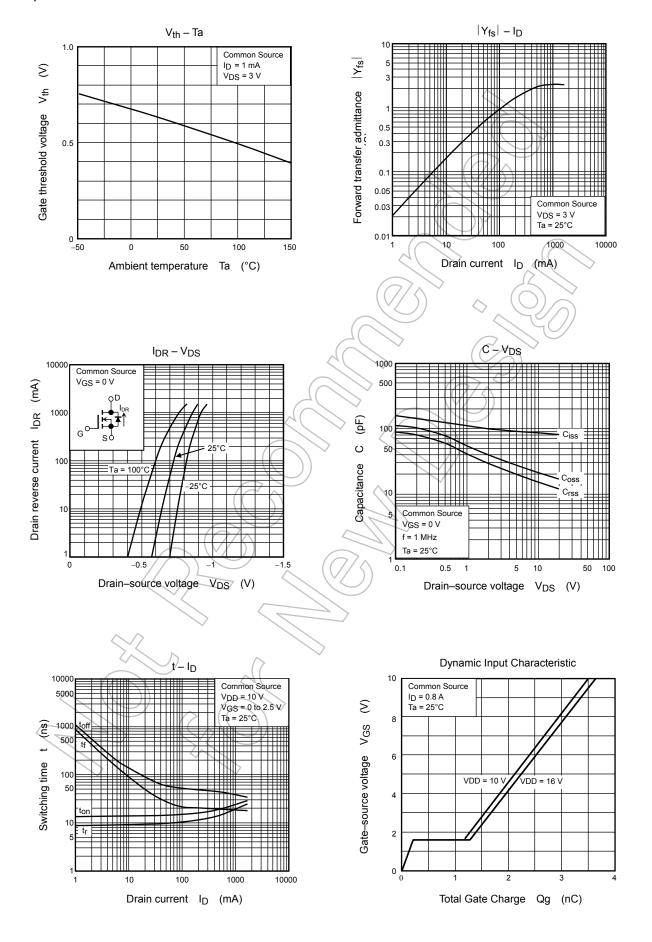




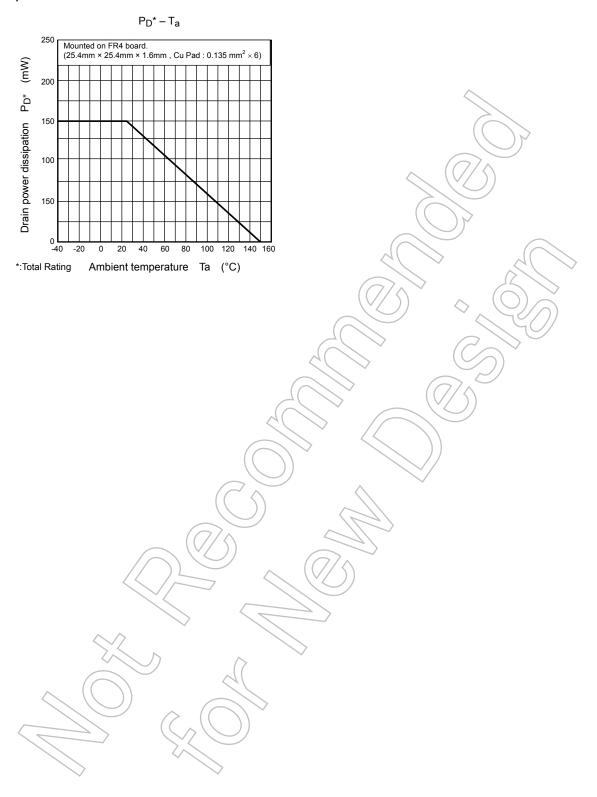


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Q1, Q2 Common



Q1, Q2 Common



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